

EECS 170A
Professor Burke Section B
Homework #5 Solutions and Grading Criteria

- 1) $I_{AD} = I_0(e^{qV_{diode}/kT} - 1)$
 $I_{AD} = (V_{AD} - V_{diode}) / 2k\Omega$ (Using Ohm's Law)
 2 Equations, 2 unknowns since I_0 and V_{AD} are given.

V_{AD} (V)	V_{diode} (V)	Acceptable Range for V_{diode}	I_{AD} (mA)	Acceptable Range for I_{AD}
0	0	0	0	0
0.5	0.496	0.48 - 0.51	0.002	0.001 - 0.003
1	0.613	0.59 - 0.62	0.193	0.1 - 0.3
1.5	0.634	0.62 - 0.64	0.433	0.3 - 0.5
2	0.646	0.63 - 0.65	0.677	.05 - 0.7
2.5	0.654	0.64 - 0.66	0.923	0.8 - 1
3	0.660	0.65 - 0.67	1.17	1 - 1.2
3.5	0.665	0.65 - 0.67	1.42	1.3 - 1.5
4	0.669	0.65 - 0.67	1.67	1.5 - 1.7
4.5	0.673	0.66 - 0.68	1.91	1.8 - 2
5	0.676	0.66 - 0.68	2.16	2 - 2.2
5.5	0.679	0.66 - 0.68	2.41	2.3 - 2.5
6	0.681	0.67 - 0.69	2.66	2.5 - 2.7
6.5	0.684	0.67 - 0.69	2.91	2.8 - 3
7	0.686	0.67 - 0.69	3.16	3 - 3.2
7.5	0.688	0.67 - 0.69	3.41	3.3 - 3.5
8	0.690	0.68 - 0.7	3.66	3.5 - 3.7
8.5	0.691	0.68 - 0.7	3.90	3.8 - 4
9	0.693	0.68 - 0.7	4.15	4 - 4.2
9.5	0.694	0.68 - 0.7	4.40	4.3 - 4.5
10	0.696	0.68 - 0.7	4.65	4.5 - 4.7

Grading: 1 pt for each answer in table.

- 2) Using the $1k\Omega$ base resistance:

- a) $V_{EB} = V_E - V_B = 0.6$ (Make sure you get this sign right. Depends on pnp or npn)
 b) $I_C = \beta I_B = 100 I_B$
 c) $I_E = I_B + I_C = 101 I_B$
 d) $I_C = (V_C + 7) / 2000$
 e) $I_B = (V_B + 3) / 1000$
 f) $I_E = -V_E / 2000$

c = f: $101 I_B = -V_E / 2000$
 e: $101(V_B + 3) / 1000 = -V_E / 2000$
 $-202(V_B + 3) = V_E$
 a: $V_E = V_B + 0.6$
 $-202(V_B + 3) = V_B + 0.6$
 $V_B = -2.99V$
 $V_E = V_B + 0.6 = -2.39V$

- e: $I_B = (V_B + 3) / 1000 = 11.8\mu A$
 b: $I_C = 100 I_B = 1.18mA$
 c: $I_E = 101 I_B = 1.19mA$
 d: $I_C = (V_C + 7) / 2000$
 $V_C = 2000I_C - 7 = -4.64V$
 $V_{BE} = V_B - V_E = -0.6V$
 $V_{CE} = V_C - V_E = -2.25V$
 $V_{BC} = V_B - V_C = 1.65V$
 Since $V_{BE} < 0$ and $V_{BC} > 0$, the pnp BJT is in active mode.

V_B	-2.99V	6 pts (no partial credit)
V_C	-4.64V	6 pts (no partial credit)
V_E	-2.39V	6 pts (no partial credit)
V_{BE}	-0.6V	6 pts (no partial credit)
V_{CE}	-2.25V	6 pts (no partial credit)
V_{BC}	1.65V	6 pts (no partial credit)
I_B	11.8μA	6 pts (no partial credit)
I_C	1.18mA	6 pts (no partial credit)
I_E	1.19mA	6 pts (no partial credit)
Active? Y or N	Yes	4 pts (no reason needed)

If a 1Ω base resistance is used, the following answers are calculated:

Equations a-d and f are the same.

e) $I_B = V_B + 3$

- e: $101(V_B + 3) = -V_E / 2000$
 $-202000(V_B + 3) = V_E$
 $-202000(V_B + 3) = V_B + 0.6$
 $V_B = -3.00V$
 $V_E = V_B + 0.6 = -2.40V$
 e: $I_B = V_B + 3 = 11.9\mu A$
 b: $I_C = 100 I_B = 1.19mA$
 c: $I_E = 101 I_B = 1.20mA$
 $V_C = 2000I_C - 7 = -4.62V$
 $V_{BE} = V_B - V_E = -0.6V$
 $V_{CE} = V_C - V_E = -2.22V$
 $V_{BC} = V_B - V_C = 1.62V$
 Since $V_{BE} < 0$ and $V_{BC} > 0$, the pnp BJT is in active mode.

V_B	-3.00V	6 pts (no partial credit)
V_C	-4.62V	6 pts (no partial credit)
V_E	-2.40V	6 pts (no partial credit)
V_{BE}	-0.6V	6 pts (no partial credit)
V_{CE}	-2.22V	6 pts (no partial credit)
V_{BC}	1.62V	6 pts (no partial credit)
I_B	11.9μA	6 pts (no partial credit)
I_C	1.19mA	6 pts (no partial credit)
I_E	1.20mA	6 pts (no partial credit)
Active? Y or N	Yes	4 pts (no reason needed)